SOT223 N-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET

Features and Benefits

- 6A Pulse Drain Current
- Fast Switching Speed
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

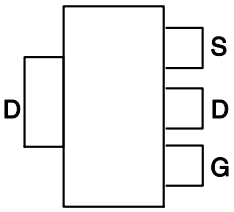
- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (e3)
- Weight: 0.112 grams (Approximate)

Applications

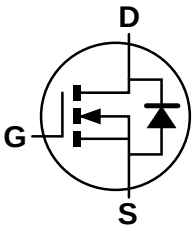
- DC-DC Converters
- Solenoids / Relay Driver for Automotive

SOT223

Top View



Pin Out - Top



Equivalent Circuit

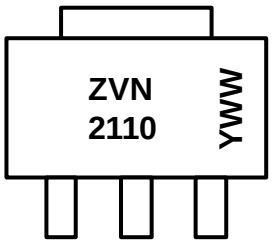
Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZVN2110GTA	ZVN2110	7	8	1,000

Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

SOT223



ZVN2110 = Product Type Marking Code
YWW = Date Code Marking
Y or $\overline{Y}$ = Last Digit of Year (ex: 5= 2015)
WW or $\overline{WW}$ = Week Code (01~53)

ABSOLUTE MAXIMUM RATINGS (@T_A = +25°C, unless otherwise stated.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	100	V
Gate-Source Voltage	V_{GSS}	±20	V
Continuous Drain Current	I_D	500	mA
Pulsed Drain Current	I_{DM}	6	A
Power Dissipation	P_D	2	W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS (@T_A = +25°C, unless otherwise stated.)

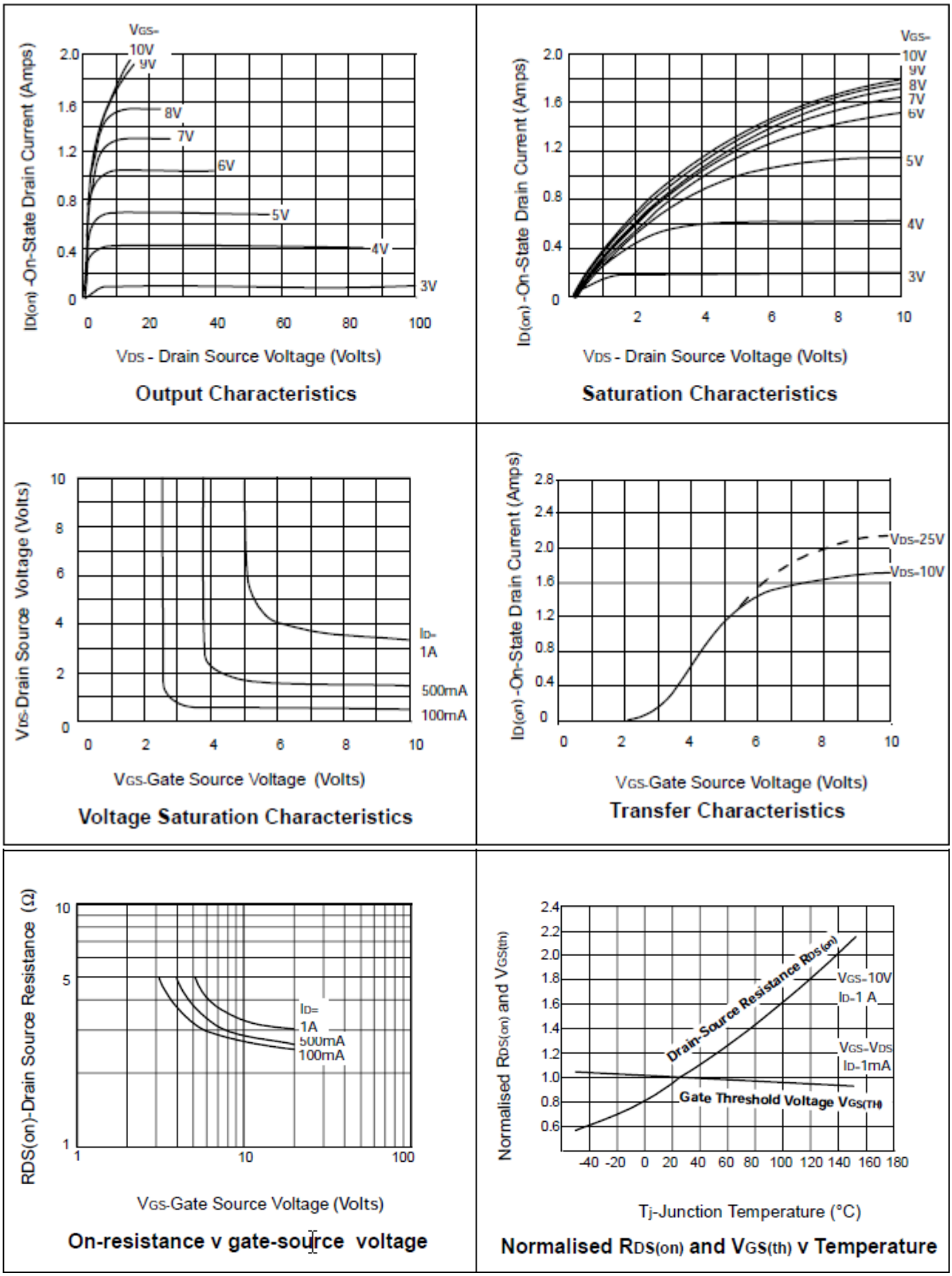
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	100	-	-	V	V_{GS} = 0V, I_D = 1mA
Zero Gate Voltage Drain Current	I_{DSS}	-	-	1 100	µA µA	V_{DS} = 100V, V_{GS} = 0V V_{DS} = 80V, V_{GS} = 0V, T= +125°C(6)
Gate-Body Leakage	I_{GSS}	-	0.1	20	nA	V_{GS} = ±20V, V_{DS} = 0V
On-State Drain Current (Note 5)	$I_{D(ON)}$	1.5	2	-	A	V_{GS} = 10V, V_{DS} = 25V
ON CHARACTERISTICS						
Gate-Source Threshold Voltage	$V_{GS(TH)}$	0.8	-	2.4	V	V_{DS} = V_{GS}, I_D = 1mA
Static Drain-Source On-State Resistance (Note 5)	$R_{DS(ON)}$	-	-	4	Ω	V_{GS} = 10V, I_D =1A
Forward Transconductance (Notes 5 & 6)	g_{fs}	250	350	-	mS	V_{DS} = 25V, I_D = 1A
DYNAMIC CHARACTERISTICS						
Input Capacitance (Note 6)	C_{iss}	-	59	75	pF	V_{DS} = 25V, V_{GS} = 0V, f = 1.0MHz
Common Source Output Capacitance (Note 6)	C_{oss}	-	16	25	pF	
Reverse Transfer Capacitance (Note 6)	C_{rss}	-	4	8	pF	
Turn-On Delay Time (Notes 6 & 7)	$t_{D(ON)}$	-	4	7	ns	V_{DD} = 25V, I_D = 1A
Rise Time (Notes 6 & 7)	t_R	-	4	8	ns	
Turn-Off Delay Time (Notes 6 & 7)	$t_{D(OFF)}$	-	8	13	ns	
Fall Time (Notes 6 & 7)	t_F	-	8	13	ns	

DRAIN-SOURCE DIODE CHARACTERISTICS

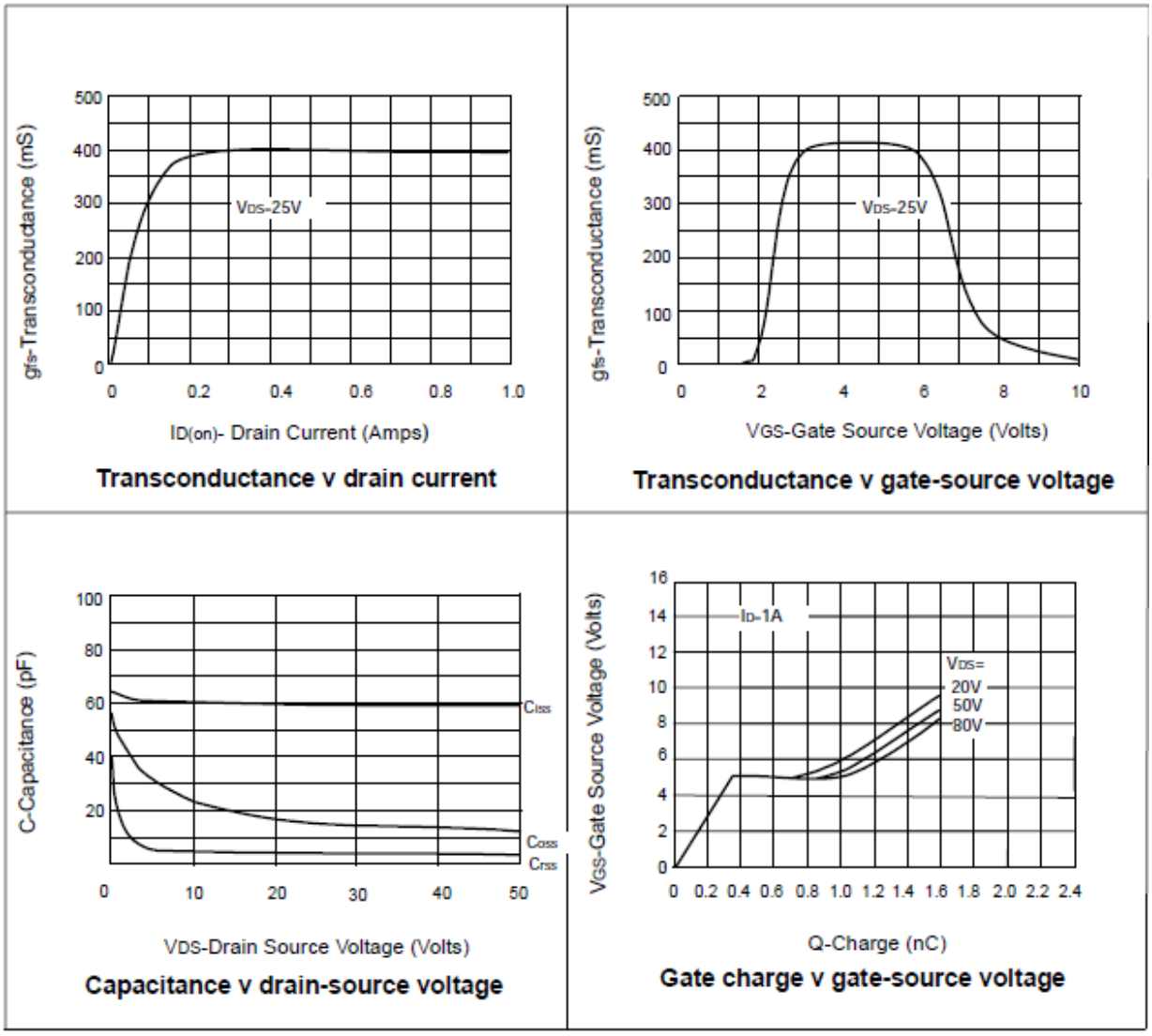
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Diode Forward Voltage (Note 5)	V_{SD}	-	0.82	-	V	I_S=0.32A, V_{GS}=0
Reverse Recovery Time	T_{RR}	-	112	-	ns	I_F=0.32A, V_{GS}=0, I_R=0.1A

Notes: 5. Measured under pulsed conditions. Width=300µs. Duty cycle ≤2%.
6. Sample test.
7. Switching times measured with 50Ω source impedance and <5ns rise time on a pulse generator.

TYPICAL CHARACTERISTICS

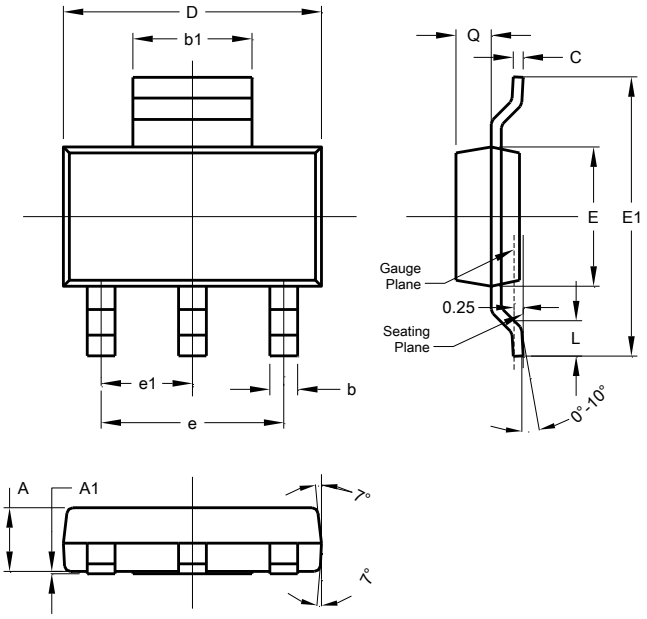


TYPICAL CHARACTERISTICS



Package Outline Dimensions

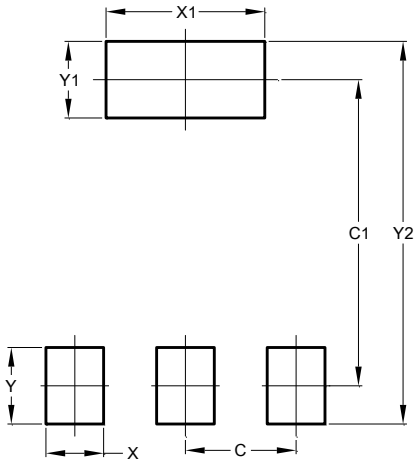
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223			
Dim	**Min**	**Max**	**Typ**
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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